

Product/Process Change Notification

N° 2021-041-A2

Dear customer,

please find attached our Infineon Technologies AG PCN:

Several changes affecting IGBTs and diodes for DSC S modules

Important information for your attention:

- Please respond to this PCN by indicating your decision on the approval form, sign it and return to your sales partner before 2022-01-23.
- Infineon aligns with the widely-recognized JEDEC STANDARD "JESD46", which stipulates:
 "Lack of acknowledgement of the PCN within 30 days constitutes acceptance of the change."
 Notwithstanding the aforesaid individual agreements shall prevail.

Your prompt reply will help Infineon to assure a smooth and well-executed transition. If Infineon does not hear from your side by the due date, we will assume your full acceptance to this proposed change and its implementation.

Your attention and response to this matter is greatly appreciated.







On 16 April 2020, Infineon acquired Cypress.

We are now in the process of merging and consolidating our tools and processes for PCN, Information Notes, Errata and Product Discontinuance.

For further details, please visit our website:

https://www.infineon.com/cms/en/about-infineon/company/cypress-acquisition/

Infineon Technologies AG

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Chairman of the Supervisory Board: Dr. Wolfgang Eder

Management Board: Dr. Reinhard Ploss (CEO), Dr. Helmut Gassel, Jochen Hanebeck, Constanze Hufenbecher, Dr. Sven Schneider

Registered Office: Neubiberg

Commercial Register: München HRB 126492



Product/Process Change Notification

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Products affected Please refer to attached affected product list 1_cip21041_A2

Detailed change information

Subject: Several changes affecting IGBTs and diodes for DSC S modules

Reason/Motivation: Secure and increase capacity for running and future products.

PROCESS - WAFER PRODUCTION: New Wafer diameter: Wafer diameter: HIG-GED1, FF450*: IGBT 200 mm and 300 mm PROCESS - WAFER PRODUCTION: Frontside metal stack with TiW Change of specified wafer process sequence (deletion and/or additional HIG-GDD1, FF400*: Diode process step) HIG-GED1, FF450*: Diode Infineon Technologies (Kulim) Sdn. Bhd., Kulim, Malaysia HIG-GED1, FF450*: IGBT Infineon Technologies Austria AG, Villach, Austria and Infineon Technologies Dresden GmbH, Dresden, Germany	Reason/Motivation:	secure and increase capacity for running and future products.		
wafer diameter 200 mm 200 mm 4IIG-GED1, FF450*: IGBT 200 mm and 300 mm PROCESS - WAFER PRODUCTION: Frontside metal stack with TiW Change of specified wafer process sequence (deletion and/or additional process step) HIG-GDD1, FF400*: Diode HIG-GDD1, FF450*: Diode HIG-GDD1, FF450*: Diode HIG-GED1, FF450*: Diode PROCESS - WAFER PRODUCTION: Move Wafer production and preassembly all or parts of production to a different wafer fab site. HIG-GDD1, FF400*: IGBT and diode HIG-GDD1, FF400*: IGBT and diode HIG-GED1, FF450*: Diode Infineon Technologies Austria AG, Villach, Austria HIG-GED1, FF450*: IGBT Infineon Technologies Austria AG, Villach, Austria HIG-GED1, FF450*: IGBT Infineon Technologies Austria AG, Villach, Austria Infineon Technologies Dresden GmbH,	Description	Old	New	
PROCESS - WAFER PRODUCTION: Frontside metal stack with TiW Change of specified wafer process sequence (deletion and/or additional HIG-GDD1, FF400*: Diode process step) HIG-GED1, FF450*: Diode PROCESS - WAFER PRODUCTION: Move Wafer production and preassembly all or parts of production to a different location wafer fab site. HIG-GDD1, FF400*: IGBT and diode HIG-GED1, FF450*: Diode HIG-GED1, FF450*: Diode HIG-GED1, FF450*: Diode Infineon Technologies Austria AG, Villach, Austria HIG-GED1, FF450*: IGBT Infineon Technologies Austria AG, Villach, Austria HIG-GED1, FF450*: IGBT Infineon Technologies Austria AG, Villach, Austria HIG-GED1, FF450*: IGBT Infineon Technologies Austria AG, Villach, Austria Infineon Technologies Dresden GmbH,	PROCESS - WAFER PRODUCTION: New	Wafer diameter:	Wafer diameter:	
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and Infineon Technologies Dresden GmbH,		_		
Infineon Technologies Dresden GmbH,		Villach, Austria		
Dresden, Germany				



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TEST FLOW: Move of all or part of Wafer test location

electrical wafer test and/or final test to

a different test site. HIG-GDD1, FF400*: IGBT and diode

HIG-GED1, FF450*: Diode

Infineon Technologies Austria AG,

Villach, Austria

HIG-GED1, FF450*: IGBT

Infineon Technologies Austria AG,

Villach, Austria

Wafer test location

HIG-GDD1, FF400*: IGBT and diode

HIG-GED1, FF450*: Diode

Infineon Technologies (Kulim) Sdn. Bhd.,

Kulim, Malaysia

HIG-GED1, FF450*: IGBT

Infineon Technologies Austria AG,

Villach, Austria

and

Infineon Technologies Dresden GmbH,

Dresden, Germany

Product identification Traceability is assured via lot number.

No change in SP ordering number.

Anticipated impact of change

Based on the qualifcation performed, Infineon does not see any influence on final

product integrity.

DeQuMa-ID(s): SEM-PW-02 / SEM-PW-12 / SEM-PW-13 / SEM-TF-01

Attachments 1_cip21041_A2 affected product list

Time schedule

Final qualification report available

First samples available on request

Intended start of delivery [1] 2022-04-01

Last order date (LOD) [2] 2022-06-08

Last delivery date (LDD) [3] 2023-06-08

If you have any questions, please do not hesitate to contact your local sales office.

^[1] provided date or earlier after customer approval

^[2] Last time buy volume to be placed latest until LOD

^[3] Delivery of new product can be earlier (see Intended start of delivery) and depends on approval



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Sales name	SP number	OPN	Package
FF400R07A01E3_S6	SP001661226	FF400R07A01E3S6XKSA2	PG-MDIP-14-1
FF450R08A03P2	SP001630036	FF450R08A03P2XKSA1	PG-MDIP-14-5